## NSN 5961-00-082-3401

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View Online at https://aerobasegroup.com/nsn/5961-00-082-3401 **Inclosure Material:** Metal **Overall Length:** Between 1.022 inches and 1.253 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.423 inches and 0.438 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 100.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 250.00 amperes peak forward surge current **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius case **Special Features:** Reversed polarity **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud **Specification Data:** 80131-release3291 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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